Accepted Manuscript

Title: Enhanced Photoelectrochemical Performance of Z-scheme g-C₃N₄/BiVO₄ Photocatalyst

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PII: S0926-3373(18)30385-0

DOI: https://doi.org/10.1016/j.apcatb.2018.04.056

Reference: APCATB 16627

To appear in: Applied Catalysis B: Environmental

Received date: 30-1-2018 Revised date: 12-4-2018 Accepted date: 22-4-2018

Please cite this article as: Safaei J, Ullah H, Mohamed NA, Noh MFM, Soh MF, Tahir AA, Ludin NA, Ibrahim MA, Wan Isahak WNR, Mat Teridi MA, Enhanced Photoelectrochemical Performance of Z-scheme g-C₃N₄/BiVO₄ Photocatalyst, *Applied Catalysis B: Environmental* (2010), https://doi.org/10.1016/j.apcatb.2018.04.056

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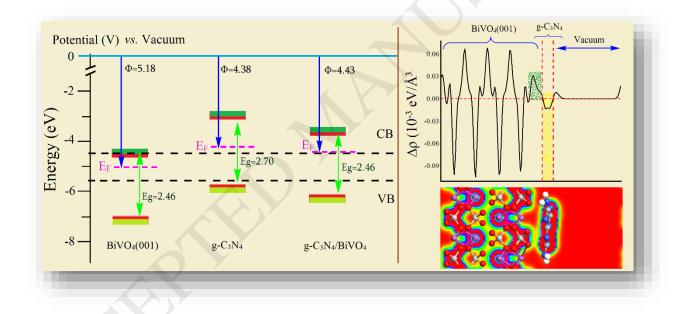
Enhanced Photoelectrochemical Performance of Z-scheme g-C₃N₄/BiVO₄ Photocatalyst

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Graphical Abstract:



Highlights

- Comparative Experimental and DFT study of g-C₃N₄/BiVO₄, Z-scheme heterojunction is performed.
- g-C₃N₄/BiVO₄ heterojunction has boosted the performance of BiVO₄ to four times.
- Highest photocurrent is obtained for g-C₃N₄/BiVO₄ (0.42 mAcm⁻² at 1.23 V vs. RHE).
- The superiority of this heterojunction is due to low mismatch (0.02%); confirmed from periodic DFT simulations.

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